

**isc Silicon NPN Power Transistor**
**2SC1080**
**DESCRIPTION**

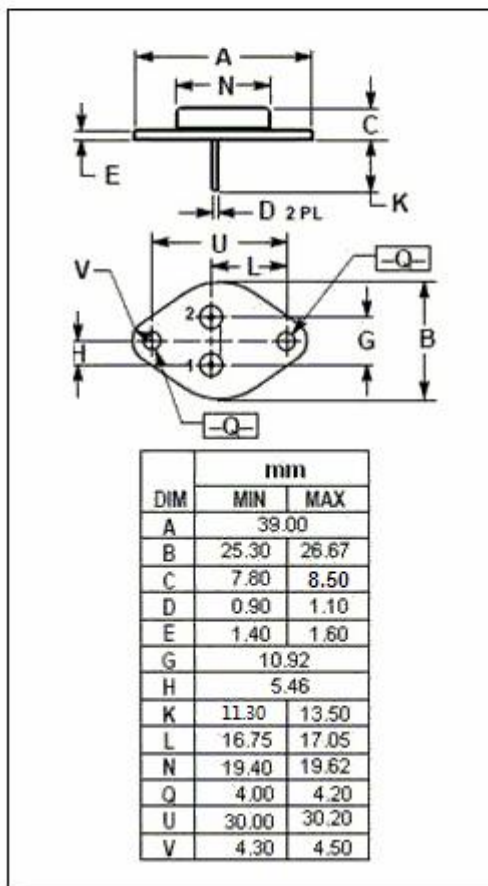
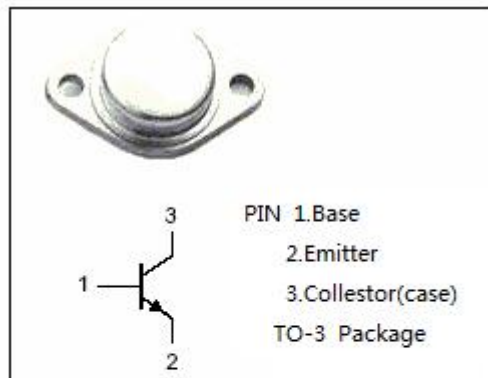
- With TO-3 Package
- High power dissipation
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- For audio power amplifier applications

**ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)**

| SYMBOL           | PARAMETER                    | VALUE   | UNIT |
|------------------|------------------------------|---------|------|
| V <sub>CBO</sub> | Collector-Base Voltage       | 110     | V    |
| V <sub>CEO</sub> | Collector-Emitter Voltage    | 110     | V    |
| V <sub>EBO</sub> | Emitter-Base Voltage         | 5       | V    |
| I <sub>C</sub>   | Collector Current-Continuous | 12      | A    |
| P <sub>C</sub>   | Collector Power Dissipation  | 100     | W    |
| T <sub>J</sub>   | Junction Temperature         | 150     | °C   |
| T <sub>stg</sub> | Storage Temperature Range    | -65~150 | °C   |



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**ELECTRICAL CHARACTERISTICS**
 $T_c=25^{\circ}\text{C}$  unless otherwise specified

| SYMBOL        | PARAMETER                            | CONDITIONS                          | MIN | TYP. | MAX | UNIT |
|---------------|--------------------------------------|-------------------------------------|-----|------|-----|------|
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=10\text{A}; I_B=1\text{A}$     |     |      | 3.0 | V    |
| $V_{BE(ON)}$  | Base-Emitter ON Voltage              | $I_C=10\text{A}; V_{CE}=5\text{V}$  |     |      | 2.5 | V    |
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage  | $I_C=10\text{mA}; I_B=0$            | 110 |      |     | V    |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage       | $I_E=1\text{mA}; I_C=0$             | 5   |      |     | V    |
| $h_{FE-1}$    | DC Current Gain                      | $I_C=2.0\text{A}; V_{CE}=5\text{V}$ | 40  |      | 140 |      |
| $h_{FE-2}$    | DC Current Gain                      | $I_C=7.0\text{A}; V_{CE}=5\text{V}$ | 15  |      |     |      |
| $f_T$         | Current-Gain—Bandwidth Product       | $I_C=2\text{A}; V_{CE}=5\text{V}$   |     | 4    |     | MHz  |

**◆  $h_{FE-1}$  Classifications**

| R     | Y      |
|-------|--------|
| 40-80 | 70-140 |

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